

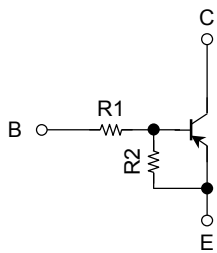
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2707JE, RN2708JE, RN2709JE

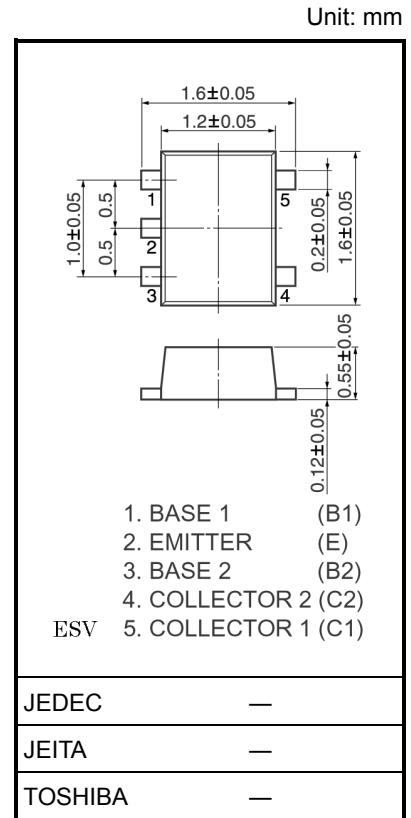
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Extreme-Super-Mini (5 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Wide range of resistor values are available to use in various circuit designs.
- Complementary to RN1707JE~1709JE

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2707JE	10	47
RN2708JE	22	47
RN2709JE	47	22

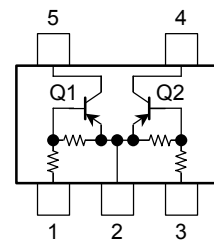


Weight: g (typ.)

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	RN1707JE~1709JE	V_{CBO}	-50	V
Collector-emitter voltage		V_{CEO}	-50	V
Emitter-base voltage	RN1707JE	V_{EBO}	-6	V
	RN1708JE		-7	
	RN1709JE		-15	
Collector current	RN1707JE~1709JE	I_C	-100	mA
Collector power dissipation		P_C (Note)	100	mW
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55~150	°C

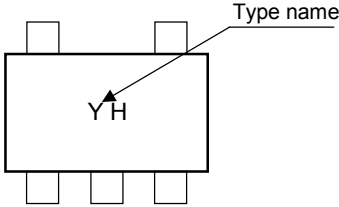
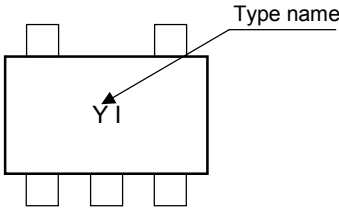
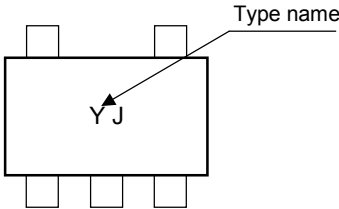
Equivalent Circuit (top view)



Note: Total rating

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2707JE~2709JE	I_{CBO}	$V_{CB} = -50\text{ V}, I_E = 0$	—	—	-100	nA
		I_{CEO}	$V_{CE} = -50\text{ V}, I_B = 0$	—	—	-500	
Emitter cut-off current	RN2707JE	I_{EBO}	$V_{EB} = -6\text{ V}, I_C = 0$	-0.081	—	-0.15	mA
	RN2708JE			-0.078	—	-0.145	
	RN2709JE			-0.167	—	-0.311	
DC current gain	RN2707JE	h_{FE}	$V_{CE} = -5\text{ V}, I_C = -10\text{ mA}$	80	—	—	
	RN2708JE			80	—	—	
	RN2709JE			70	—	—	
Collector-emitter saturation voltage	RN2707JE~2709JE	$V_{CE(sat)}$	$I_C = -5\text{ mA}, I_B = -0.25\text{ mA}$	—	-0.1	-0.3	V
Input voltage (ON)	RN2707JE	$V_{I(ON)}$	$V_{CE} = -0.2\text{ V}, I_C = -5\text{ mA}$	-0.7	—	-1.8	V
	RN2708JE			-1.0	—	-2.6	
	RN2709JE			-2.2	—	-5.8	
Input voltage (OFF)	RN2707JE	$V_{I(OFF)}$	$V_{CE} = -5\text{ V}, I_C = -0.1\text{ mA}$	-0.5	—	-1.0	V
	RN2708JE			-0.6	—	-1.16	
	RN2709JE			-1.5	—	-2.6	
Transition frequency	RN2707JE~2709JE	f_T	$V_{CE} = -10\text{ V}, I_C = -5\text{ mA}$	—	200	—	MHz
Collector output capacitance	RN2707JE~2710JE	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3	6	pF
Input resistor	RN2707JE	R1	—	7	10	13	k Ω
	RN2708JE			15.4	22	28.6	
	RN2709JE			32.9	47	61.1	
Resistor ratio	RN2707JE	R1/R2	—	0.191	0.213	0.232	
	RN2708JE			0.421	0.468	0.515	
	RN2709JE			1.92	2.14	2.35	

Type Name	Marking
RN2707JE	 A schematic diagram of a rectangular component with four pins (two on top, two on bottom). The marking 'YH' is centered on the component. An arrow labeled 'Type name' points to the 'H' in 'YH'.
RN2708JE	 A schematic diagram of a rectangular component with four pins (two on top, two on bottom). The marking 'YI' is centered on the component. An arrow labeled 'Type name' points to the 'I' in 'YI'.
RN2709JE	 A schematic diagram of a rectangular component with four pins (two on top, two on bottom). The marking 'YJ' is centered on the component. An arrow labeled 'Type name' points to the 'J' in 'YJ'.

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